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JANUARY 2014

FDY302NZ

Single N-Channel 2.5V Specified PowerTrench® MOSFET

General Description

This Single N-Channel MOSFET has been designed using Fairchild Semiconductor's advanced Power Trench process to optimize the $R_{\text{DS(ON)}} \textcircled{Q} V_{\text{GS}} = 2.5 \text{V}.$

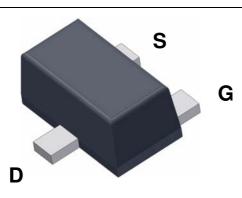
Applications

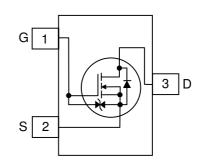
• Li-Ion Battery Pack



Features

- 600 mA, 20 V $R_{DS(ON)}=~300$ m Ω @ $V_{GS}=4.5$ V $R_{DS(ON)}=~500$ m Ω @ $V_{GS}=2.5$ V
- ESD protection diode (note 3)
- · RoHS Compliant





Absolute Maximum Ratings TA=25°C unless otherwise noted

Symbol	Parameter		Ratings	Unit s
V_{DS}	Drain-Source Voltage		20	V
V_{GS}	Gate-Source Voltage		± 12	V
I_D	Drain Current - Continuous	(Note 1a)	600	mA
	- Pulsed		1000	
P_D	Power Dissipation (Steady State)	(Note 1a)	625	mW
		(Note 1b)	446	
T_{J},T_{STG}	Operating and Storage Junction Temperature Range		−55 to +150	°C

Thermal Characteristics

R _{eJA}	Thermal Resistance, Junction-to-Ambient (Note 1a)	200	°C/W
Rain	Thermal Resistance, Junction-to-Ambient (Note 1b)	280	

Package Marking and Ordering Information

Device Marking		Device	Reel Size	Tape width	Quantity
	F	FDY302NZ	7 "	8 mm	3000 units

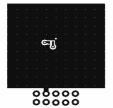
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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics			1		
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0~V, \qquad I_D=250~\mu A$	20			V
ΔBV _{DSS} ΔT _J	Breakdown Voltage Temperature Coefficient	I_D = 250 μ A, Referenced to 25°C		15		mV/°C
DSS	Zero Gate Voltage Drain Current	$V_{DS} = 16 \text{ V}, \qquad V_{GS} = 0 \text{ V}$			1	μΑ
I _{GSS}	Gate-Body Leakage,	$V_{GS} = \pm 12 \text{ V}, V_{DS} = 0 \text{ V}$			± 10	μΑ
		$V_{GS} = \pm 4.5 \text{ V}, V_{DS} = 0 \text{ V}$			± 1	μA
On Chara	acteristics (Note 2)					
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	0.6	1.0	1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	I_D = 250 μ A, Referenced to 25°C		3		mV/°C
$R_{DS(on)}$	Static Drain-Source	$V_{GS} = 4.5 \text{ V}, I_D = 600 \text{ mA}$		0.24	0.30	Ω
	On–Resistance	$V_{GS} = 2.5 \text{ V}, I_{D} = 500 \text{ mA}$ $V_{GS} = 1.8 \text{ V}, I_{D} = 150 \text{ mA}$		0.36 0.70	0.50 1.20	
		$V_{GS} = 1.5 \text{ V}, I_D = 130 \text{ m/s}$ $V_{GS} = 4.5 \text{ V}, I_D = 600 \text{mA}, T_J = 125 ^{\circ}\text{C}$		0.75	1.00	
]FS	Forward Transconductance	$V_{DS} = 5 \text{ V}, \qquad I_{D} = 600 \text{ mA}$		1.8		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = 10 \text{ V}, \qquad V_{GS} = 0 \text{ V},$		60		pF
Coss	Output Capacitance	f = 1.0 MHz		20		pF
C _{rss}	Reverse Transfer Capacitance			10		pF
Switchin	g Characteristics (Note 2)					
d(on)	Turn-On Delay Time	$V_{DD} = 10 \text{ V}, \qquad I_{D} = 1 \text{ A},$		6	12	ns
tr	Turn-On Rise Time	$V_{GS} = 4.5 \; V, \qquad R_{GEN} = 6 \; \Omega$		8	16	ns
d(off)	Turn-Off Delay Time			8	16	ns
f	Turn-Off Fall Time			2.4	4.8	ns
Q_g	Total Gate Charge	$V_{DS} = 10 \text{ V}, \qquad I_{D} = 600 \text{ mA},$		8.0	1.1	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = 4.5 \text{ V}$		0.16		nC
Q _{gd}	Gate-Drain Charge			0.26		nC
Drain–Sc	ource Diode Characteristics	and Maximum Ratings				
s	Maximum Continuous Drain to Source Diode Forward Current				600	mA
SM	Maximum Continuous Drain to Source	e Diode Forward Current - Pusled			1000	mA
V _{SD}	Drain–Source Diode Forward Voltage	$V_{\text{GS}} = 0 \ V, \ I_{\text{S}} = 150 \ \text{mA} \ \ \text{(Note 2)}$		0.7	1.2	V
t _{rr}	Diode Reverse Recovery Time	$I_F = 600 \text{ mA},$		8		nS
Q _{rr}	Diode Reverse Recovery Charge	dI _F /dt = 100 A/μs		1		nC

Notes:

1. R_{BJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.



200 °C/W when mounted on a 1in² pad of 2 oz copper



- b) 280°C/W when mounted on a minimum pad of 2 oz copper Scale 1 : 1 on letter size paper
- 2. Pulse Test: Pulse Width $< 300 \mu s$, Duty Cycle < 2.0%
- The diode connected between the gate and source serves only as protection againts ESD. No gate overvoltage rating is implied.

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Typical Characteristics

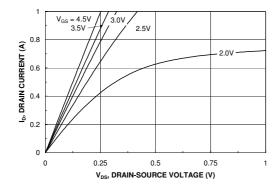


Figure 1. On-Region Characteristics.

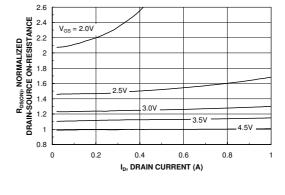


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.

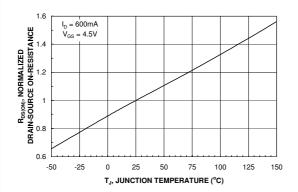


Figure 3. On-Resistance Variation with Temperature.

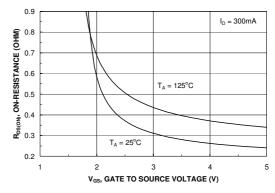


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

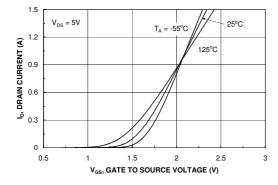


Figure 5. Transfer Characteristics.

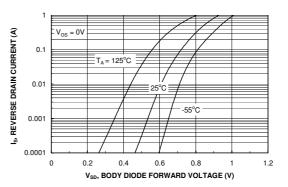
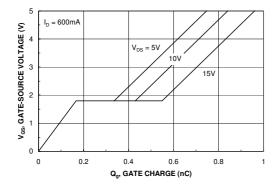


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.

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Typical Characteristics



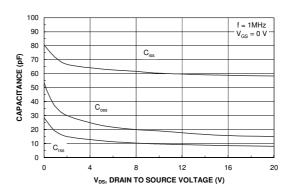
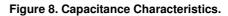
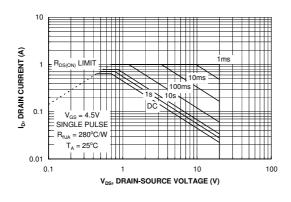


Figure 7. Gate Charge Characteristics.





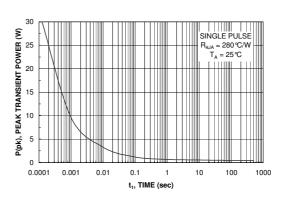


Figure 9. Maximum Safe Operating Area.

Figure 10. Single Pulse Maximum Power Dissipation.

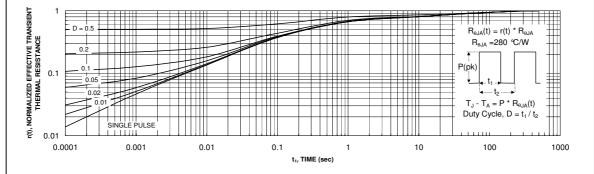
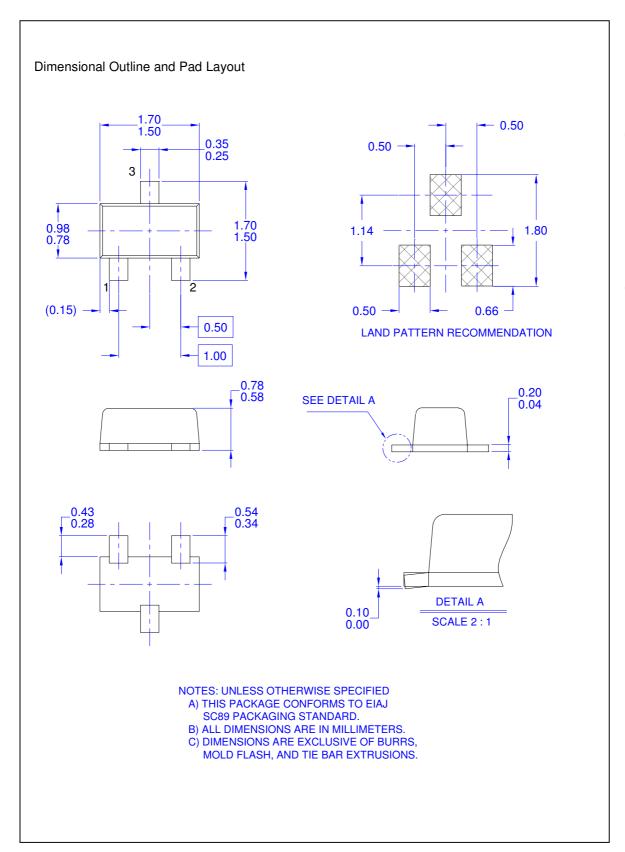


Figure 11. Transient Thermal Response Curve.

Thermal characterization performed using the conditions described in Note 1b. Transient thermal response will change depending on the circuit board design.

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